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AMD Xilinx - XC2S50-5FGG256C Datasheet



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Understanding <u>Embedded - FPGAs (Field</u> <u>Programmable Gate Array)</u>

Embedded - FPGAs, or Field Programmable Gate Arrays, are advanced integrated circuits that offer unparalleled flexibility and performance for digital systems. Unlike traditional fixed-function logic devices, FPGAs can be programmed and reprogrammed to execute a wide array of logical operations, enabling customized functionality tailored to specific applications. This reprogrammability allows developers to iterate designs quickly and implement complex functions without the need for custom hardware.

Applications of Embedded - FPGAs

The versatility of Embedded - FPGAs makes them indispensable in numerous fields. In telecommunications.

Details

Product Status	Active
Number of LABs/CLBs	384
Number of Logic Elements/Cells	1728
Total RAM Bits	32768
Number of I/O	176
Number of Gates	50000
Voltage - Supply	2.375V ~ 2.625V
Mounting Type	Surface Mount
Operating Temperature	0°C ~ 85°C (TJ)
Package / Case	256-BGA
Supplier Device Package	256-FBGA (17x17)
Purchase URL	https://www.e-xfl.com/product-detail/xilinx/xc2s50-5fgg256c

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Address: Room A, 16/F, Full Win Commercial Centre, 573 Nathan Road, Mongkok, Hong Kong

Spartan-II Product Availability

Table 2 shows the maximum user I/Os available on the device and the number of user I/Os available for each device/package combination. The four global clock pins are usable as additional user I/Os when not used as a global clock pin. These pins are not included in user I/O counts.

Table 2: Spartan-II FPGA User I/O Chart(1)

		Available User I/O According to Package Type					
Device	Maximum User I/O	VQ100 VQG100	TQ144 TQG144	CS144 CSG144	PQ208 PQG208	FG256 FGG256	FG456 FGG456
XC2S15	86	60	86	(Note 2)	-	-	-
XC2S30	92	60	92	92	(Note 2)	-	-
XC2S50	176	-	92	-	140	176	-
XC2S100	176	-	92	-	140	176	(Note 2)
XC2S150	260	-	-	-	140	176	260
XC2S200	284	-	-	-	140	176	284

Notes:

1. All user I/O counts do not include the four global clock/user input pins.

2. Discontinued by PDN2004-01.

drivers are disabled. Maintaining a valid logic level in this way helps eliminate bus chatter.

Because the weak-keeper circuit uses the IOB input buffer to monitor the input level, an appropriate V_{REF} voltage must be provided if the signaling standard requires one. The provision of this voltage must comply with the I/O banking rules.

I/O Banking

Some of the I/O standards described above require V_{CCO} and/or V_{REF} voltages. These voltages are externally connected to device pins that serve groups of IOBs, called banks. Consequently, restrictions exist about which I/O standards can be combined within a given bank.

Eight I/O banks result from separating each edge of the FPGA into two banks (see Figure 3). Each bank has multiple V_{CCO} pins which must be connected to the same voltage. Voltage is determined by the output standards in use.



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Figure 3: Spartan-II I/O Banks

Within a bank, output standards may be mixed only if they use the same V_{CCO} . Compatible standards are shown in Table 4. GTL and GTL+ appear under all voltages because their open-drain outputs do not depend on V_{CCO} .

Table 4: Compatible Output Standards

V _{cco}	Compatible Standards
3.3V	PCI, LVTTL, SSTL3 I, SSTL3 II, CTT, AGP, GTL, GTL+
2.5V	SSTL2 I, SSTL2 II, LVCMOS2, GTL, GTL+
1.5V	HSTL I, HSTL III, HSTL IV, GTL, GTL+

Some input standards require a user-supplied threshold voltage, V_{REF} In this case, certain user-I/O pins are

automatically configured as inputs for the V_{REF} voltage. About one in six of the I/O pins in the bank assume this role.

 V_{REF} pins within a bank are interconnected internally and consequently only one V_{REF} voltage can be used within each bank. All V_{REF} pins in the bank, however, must be connected to the external voltage source for correct operation.

In a bank, inputs requiring V_{REF} can be mixed with those that do not but only one V_{REF} voltage may be used within a bank. Input buffers that use V_{REF} are not 5V tolerant. LVTTL, LVCMOS2, and PCI are 5V tolerant. The V_{CCO} and V_{REF} pins for each bank appear in the device pinout tables.

Within a given package, the number of V_{REF} and V_{CCO} pins can vary depending on the size of device. In larger devices, more I/O pins convert to V_{REF} pins. Since these are always a superset of the V_{REF} pins used for smaller devices, it is possible to design a PCB that permits migration to a larger device. All V_{REF} pins for the largest device anticipated must be connected to the V_{REF} voltage, and not used for I/O.

Independent Banks Available

Package	VQ100	CS144	FG256
	PQ208	TQ144	FG456
Independent Banks	1	4	8

Configurable Logic Block

The basic building block of the Spartan-II FPGA CLB is the logic cell (LC). An LC includes a 4-input function generator, carry logic, and storage element. Output from the function generator in each LC drives the CLB output and the D input of the flip-flop. Each Spartan-II FPGA CLB contains four LCs, organized in two similar slices; a single slice is shown in Figure 4.

In addition to the four basic LCs, the Spartan-II FPGA CLB contains logic that combines function generators to provide functions of five or six inputs.

Look-Up Tables

Spartan-II FPGA function generators are implemented as 4-input look-up tables (LUTs). In addition to operating as a function generator, each LUT can provide a 16 x 1-bit synchronous RAM. Furthermore, the two LUTs within a slice can be combined to create a 16 x 2-bit or 32 x 1-bit synchronous RAM, or a 16 x 1-bit dual-port synchronous RAM.

The Spartan-II FPGA LUT can also provide a 16-bit shift register that is ideal for capturing high-speed or burst-mode data. This mode can also be used to store data in applications such as Digital Signal Processing.



Figure 4: Spartan-II CLB Slice (two identical slices in each CLB)

Storage Elements

Storage elements in the Spartan-II FPGA slice can be configured either as edge-triggered D-type flip-flops or as level-sensitive latches. The D inputs can be driven either by function generators within the slice or directly from slice inputs, bypassing the function generators.

In addition to Clock and Clock Enable signals, each slice has synchronous set and reset signals (SR and BY). SR forces a storage element into the initialization state specified for it in the configuration. BY forces it into the opposite state. Alternatively, these signals may be configured to operate asynchronously.

All control signals are independently invertible, and are shared by the two flip-flops within the slice.

Additional Logic

The F5 multiplexer in each slice combines the function generator outputs. This combination provides either a function generator that can implement any 5-input function, a 4:1 multiplexer, or selected functions of up to nine inputs.

Similarly, the F6 multiplexer combines the outputs of all four function generators in the CLB by selecting one of the F5-multiplexer outputs. This permits the implementation of any 6-input function, an 8:1 multiplexer, or selected functions of up to 19 inputs.

Each CLB has four direct feedthrough paths, one per LC. These paths provide extra data input lines or additional local routing that does not consume logic resources.

Arithmetic Logic

Dedicated carry logic provides capability for high-speed arithmetic functions. The Spartan-II FPGA CLB supports two separate carry chains, one per slice. The height of the carry chains is two bits per CLB.

The arithmetic logic includes an XOR gate that allows a 1-bit full adder to be implemented within an LC. In addition, a dedicated AND gate improves the efficiency of multiplier implementation.

The dedicated carry path can also be used to cascade function generators for implementing wide logic functions.

BUFTs

Each Spartan-II FPGA CLB contains two 3-state drivers (BUFTs) that can drive on-chip busses. See "Dedicated Routing," page 12. Each Spartan-II FPGA BUFT has an independent 3-state control pin and an independent input pin.

Block RAM

Spartan-II FPGAs incorporate several large block RAM memories. These complement the distributed RAM Look-Up Tables (LUTs) that provide shallow memory structures implemented in CLBs.

Block RAM memory blocks are organized in columns. All Spartan-II devices contain two such columns, one along each vertical edge. These columns extend the full height of the chip. Each memory block is four CLBs high, and consequently, a Spartan-II device eight CLBs high will contain two memory blocks per column, and a total of four blocks.

Table 5: Spartan-II Block RAM Amounts

Spartan-II Device	# of Blocks	Total Block RAM Bits
XC2S15	4	16K
XC2S30	6	24K
XC2S50	8	32K
XC2S100	10	40K
XC2S150	12	48K
XC2S200	14	56K

Each block RAM cell, as illustrated in Figure 5, is a fully synchronous dual-ported 4096-bit RAM with independent control signals for each port. The data widths of the two ports can be configured independently, providing built-in bus-width conversion.



Figure 5: Dual-Port Block RAM

Table 6 shows the depth and width aspect ratios for the block RAM.

Table	6 [.]	Block	RAM	Port	Aspect	Ratios
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Width	Depth	ADDR Bus	Data Bus
1	4096	ADDR<11:0>	DATA<0>
2	2048	ADDR<10:0>	DATA<1:0>
4	1024	ADDR<9:0>	DATA<3:0>
8	512	ADDR<8:0>	DATA<7:0>
16	256	ADDR<7:0>	DATA<15:0>

The Spartan-II FPGA block RAM also includes dedicated routing to provide an efficient interface with both CLBs and other block RAMs.

Programmable Routing Matrix

It is the longest delay path that limits the speed of any worst-case design. Consequently, the Spartan-II routing architecture and its place-and-route software were defined in a single optimization process. This joint optimization minimizes long-path delays, and consequently, yields the best system performance.

The joint optimization also reduces design compilation times because the architecture is software-friendly. Design cycles are correspondingly reduced due to shorter design iteration times. Boundary-scan operation is independent of individual IOB configurations, and unaffected by package type. All IOBs, including unbonded ones, are treated as independent 3-state bidirectional pins in a single scan chain. Retention of the bidirectional test capability after configuration facilitates the testing of external interconnections.

Table 7 lists the boundary-scan instructions supported in Spartan-II FPGAs. Internal signals can be captured during EXTEST by connecting them to unbonded or unused IOBs. They may also be connected to the unused outputs of IOBs defined as unidirectional input pins.

Boundary-Scan Command	Binary Code[4:0]	Description
EXTEST	00000	Enables boundary-scan EXTEST operation
SAMPLE	00001	Enables boundary-scan SAMPLE operation
USR1	00010	Access user-defined register 1
USR2	00011	Access user-defined register 2
CFG_OUT	00100	Access the configuration bus for Readback
CFG_IN	00101	Access the configuration bus for Configuration
INTEST	00111	Enables boundary-scan INTEST operation
USRCODE	01000	Enables shifting out USER code
IDCODE	01001	Enables shifting out of ID Code
HIZ	01010	Disables output pins while enabling the Bypass Register
JSTART	01100	Clock the start-up sequence when StartupClk is TCK
BYPASS	11111	Enables BYPASS
RESERVED	All other codes	Xilinx [®] reserved instructions

Table 7: Boundary-Scan Instructions

The public boundary-scan instructions are available prior to configuration. After configuration, the public instructions remain available together with any USERCODE instructions installed during the configuration. While the SAMPLE and BYPASS instructions are available during configuration, it is recommended that boundary-scan operations not be performed during this transitional period.

In addition to the test instructions outlined above, the boundary-scan circuitry can be used to configure the FPGA, and also to read back the configuration data.

To facilitate internal scan chains, the User Register provides three outputs (Reset, Update, and Shift) that represent the corresponding states in the boundary-scan internal state machine.

Master Serial Mode

In Master Serial mode, the CCLK output of the FPGA drives a Xilinx PROM which feeds a serial stream of configuration data to the FPGA's DIN input. Figure 15 shows a Master Serial FPGA configuring a Slave Serial FPGA from a PROM. A Spartan-II device in Master Serial mode should be connected as shown for the device on the left side. Master Serial mode is selected by a <00x> on the mode pins (M0, M1, M2). The PROM RESET pin is driven by INIT, and CE input is driven by DONE. The interface is identical to the slave serial mode except that an oscillator internal to the FPGA is used to generate the configuration clock (CCLK). Any of a number of different frequencies ranging from 4 to 60 MHz can be set using the ConfigRate option in the Xilinx software. On power-up, while the first 60 bytes of the configuration data are being loaded, the CCLK frequency is always 2.5 MHz. This frequency is used until the ConfigRate bits, part of the configuration file, have been loaded into the FPGA, at which point, the frequency changes to the selected ConfigRate. Unless a different frequency is specified in the design, the default ConfigRate is 4 MHz. The frequency of the CCLK signal created by the internal oscillator has a variance of +45%, -30% from the specified value.

Figure 17 shows the timing for Master Serial configuration. The FPGA accepts one bit of configuration data on each rising CCLK edge. After the FPGA has been loaded, the data for the next device in a daisy-chain is presented on the DOUT pin after the rising CCLK edge.



Figure 17: Master Serial Mode Timing

Slave Parallel Mode

The Slave Parallel mode is the fastest configuration option. Byte-wide data is written into the FPGA. A BUSY flag is provided for controlling the flow of data at a clock frequency F_{CCNH} above 50 MHz.

Figure 18, page 24 shows the connections for two Spartan-II devices using the Slave Parallel mode. Slave Parallel mode is selected by a <011> on the mode pins (M0, M1, M2).

If a configuration file of the format .bit, .rbt, or non-swapped HEX is used for parallel programming, then the most significant bit (i.e. the left-most bit of each configuration byte, as displayed in a text editor) must be routed to the D0 input on the FPGA. The agent controlling configuration is not shown. Typically, a processor, a microcontroller, or CPLD controls the Slave Parallel interface. The controlling agent provides byte-wide configuration data, CCLK, a Chip Select (\overline{CS}) signal and a Write signal (WRITE). If BUSY is asserted (High) by the FPGA, the data must be held until BUSY goes Low.

After configuration, the pins of the Slave Parallel port (D0-D7) can be used as additional user I/O. Alternatively, the port may be retained to permit high-speed 8-bit readback. Then data can be read by de-asserting WRITE. See "Readback," page 25.

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Figure 33: Timing Diagram for Single-Port Block RAM Memory



Figure 34: Timing Diagram for a True Dual-Port Read/Write Block RAM Memory

PCI — Peripheral Component Interface

The Peripheral Component Interface (PCI) standard specifies support for both 33 MHz and 66 MHz PCI bus applications. It uses a LVTTL input buffer and a push-pull output buffer. This standard does not require the use of a reference voltage (V_{REF}) or a board termination voltage (V_{TT}), however, it does require a 3.3V output source voltage (V_{CCO}). I/Os configured for the PCI, 33 MHz, 5V standard are also 5V-tolerant.

GTL — Gunning Transceiver Logic Terminated

The Gunning Transceiver Logic (GTL) standard is a high-speed bus standard (JESD8.3). Xilinx has implemented the terminated variation of this standard. This standard requires a differential amplifier input buffer and an open-drain output buffer.

GTL+ — Gunning Transceiver Logic Plus

The Gunning Transceiver Logic Plus (GTL+) standard is a high-speed bus standard (JESD8.3).

HSTL — High-Speed Transceiver Logic

The High-Speed Transceiver Logic (HSTL) standard is a general purpose high-speed, 1.5V bus standard (EIA/JESD 8-6). This standard has four variations or classes. Versatile I/O devices support Class I, III, and IV. This standard requires a Differential Amplifier input buffer and a Push-Pull output buffer.

SSTL3 — Stub Series Terminated Logic for 3.3V

The Stub Series Terminated Logic for 3.3V (SSTL3) standard is a general purpose 3.3V memory bus standard (JESD8-8). This standard has two classes, I and II. Versatile I/O devices support both classes for the SSTL3 standard. This standard requires a Differential Amplifier input buffer and an Push-Pull output buffer.

SSTL2 — Stub Series Terminated Logic for 2.5V

The Stub Series Terminated Logic for 2.5V (SSTL2) standard is a general purpose 2.5V memory bus standard (JESD8-9). This standard has two classes, I and II. Versatile I/O devices support both classes for the SSTL2 standard. This standard requires a Differential Amplifier input buffer and an Push-Pull output buffer.

CTT — Center Tap Terminated

The Center Tap Terminated (CTT) standard is a 3.3V memory bus standard (JESD8-4). This standard requires a Differential Amplifier input buffer and a Push-Pull output buffer.

AGP-2X — Advanced Graphics Port

The AGP standard is a 3.3V Advanced Graphics Port-2X bus standard used with processors for graphics applications. This standard requires a Push-Pull output buffer and a Differential Amplifier input buffer.

Library Primitives

The Xilinx library includes an extensive list of primitives designed to provide support for the variety of Versatile I/O features. Most of these primitives represent variations of the five generic Versatile I/O primitives:

- IBUF (input buffer)
- IBUFG (global clock input buffer)
- OBUF (output buffer)
- OBUFT (3-state output buffer)
- IOBUF (input/output buffer)

These primitives are available with various extensions to define the desired I/O standard. However, it is recommended that customers use a a property or attribute on the generic primitive to specify the I/O standard. See "Versatile I/O Properties".

IBUF

Signals used as inputs to the Spartan-II device must source an input buffer (IBUF) via an external input port. The generic IBUF primitive appears in Figure 35. The assumed standard is LVTTL when the generic IBUF has no specified extension or property.



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Figure 35: Input Buffer (IBUF) Primitive

When the IBUF primitive supports an I/O standard such as LVTTL, LVCMOS, or PCI33_5, the IBUF automatically configures as a 5V tolerant input buffer unless the V_{CCO} for the bank is less than 2V. If the single-ended IBUF is placed in a bank with an HSTL standard (V_{CCO} < 2V), the input buffer is not 5V tolerant.

The voltage reference signal is "banked" within the Spartan-II device on a half-edge basis such that for all packages there are eight independent V_{REF} banks internally. See Figure 36 for a representation of the I/O banks. Within each bank approximately one of every six I/O pins is automatically configured as a V_{REF} input.

IBUF placement restrictions require that any differential amplifier input signals within a bank be of the same standard. How to specify a specific location for the IBUF via

Input/Output		V _{IL}	V	н	V _{OL}	V _{OH}	I _{OL}	I _{ОН}
Standard	V, Min	V, Max	V, Min	V, Max	V, Max	V, Min	mA	mA
CTT	-0.5	V _{REF} – 0.2	V _{REF} + 0.2	3.6	V _{REF} – 0.4	V _{REF} + 0.4	8	-8
AGP	-0.5	V _{REF} – 0.2	V _{REF} + 0.2	3.6	10% V _{CCO}	90% V _{CCO}	Note (2)	Note (2)

Notes:

1. V_{OL} and V_{OH} for lower drive currents are sample tested.

2. Tested according to the relevant specifications.

Switching Characteristics

All devices are 100% functionally tested. Internal timing parameters are derived from measuring internal test patterns. Listed below are representative values. For more specific, more precise, and worst-case guaranteed data, use the values reported by the static timing analyzer (TRCE in the Xilinx Development System) and back-annotated to the simulation netlist. All timing parameters assume worst-case operating conditions (supply voltage and junction temperature). Values apply to all Spartan-II devices unless otherwise noted.

Global Clock Input to Output Delay for LVTTL, with DLL (Pin-to-Pin)⁽¹⁾

			S	peed Grad	le	
			All	-6	-5	
Symbol	Description	Device	Min	Max	Max	Units
T _{ICKOFDLL}	Global clock input to output delay using output flip-flop for LVTTL, 12 mA, fast slew rate, <i>with</i> DLL.	All		2.9	3.3	ns

Notes:

1. Listed above are representative values where one global clock input drives one vertical clock line in each accessible column, and where all accessible IOB and CLB flip-flops are clocked by the global clock net.

- Output timing is measured at 1.4V with 35 pF external capacitive load for LVTTL. The 35 pF load does not apply to the Min values. For other I/O standards and different loads, see the tables "Constants for Calculating TIOOP" and "Delay Measurement Methodology," page 60.
- 3. DLL output jitter is already included in the timing calculation.
- 4. For data *output* with different standards, adjust delays with the values shown in "IOB Output Delay Adjustments for Different Standards," page 59. For a global clock input with standards other than LVTTL, adjust delays with values from the "I/O Standard Global Clock Input Adjustments," page 61.

Global Clock Input to Output Delay for LVTTL, *without* DLL (Pin-to-Pin)⁽¹⁾

			All	-6	-5	
Symbol	Description	Device	Min	Max	Max	Units
T _{ICKOF}	Global clock input to output delay	XC2S15		4.5	5.4	ns
	using output flip-flop for LVTTL,	XC2S30		4.5	5.4	ns
	12 mA, fast slew rate, <i>without</i> DLL.	XC2S50		4.5	5.4	ns
		XC2S100		4.6	5.5	ns
		XC2S150		4.6	5.5	ns
		XC2S200		4.7	5.6	ns

Notes:

1. Listed above are representative values where one global clock input drives one vertical clock line in each accessible column, and where all accessible IOB and CLB flip-flops are clocked by the global clock net.

- Output timing is measured at 1.4V with 35 pF external capacitive load for LVTTL. The 35 pF load does not apply to the Min values. For other I/O standards and different loads, see the tables "Constants for Calculating TIOOP" and "Delay Measurement Methodology," page 60.
- For data *output* with different standards, adjust delays with the values shown in "IOB Output Delay Adjustments for Different Standards," page 59. For a global clock input with standards other than LVTTL, adjust delays with values from the "I/O Standard Global Clock Input Adjustments," page 61.

IOB Input Delay Adjustments for Different Standards⁽¹⁾

Input delays associated with the pad are specified for LVTTL. For other standards, adjust the delays by the values shown. A delay adjusted in this way constitutes a worst-case limit.

			Speed	l Grade	
Symbol	Description	Standard	-6	-5	Units
Data Input	Delay Adjustments				
T _{ILVTTL}	Standard-specific data input delay	LVTTL	0	0	ns
T _{ILVCMOS2}	adjustments	LVCMOS2	-0.04	-0.05	ns
T _{IPCI33_3}		PCI, 33 MHz, 3.3V	-0.11	-0.13	ns
T _{IPCI33_5}		PCI, 33 MHz, 5.0V	0.26	0.30	ns
T _{IPCI66_3}		PCI, 66 MHz, 3.3V	-0.11	-0.13	ns
T _{IGTL}		GTL	0.20	0.24	ns
T _{IGTLP}		GTL+	0.11	0.13	ns
T _{IHSTL}		HSTL	0.03	0.04	ns
T _{ISSTL2}		SSTL2	-0.08	-0.09	ns
T _{ISSTL3}		SSTL3	-0.04	-0.05	ns
T _{ICTT}		CTT	0.02	0.02	ns
T _{IAGP}		AGP	-0.06	-0.07	ns

Notes:

1. Input timing for LVTTL is measured at 1.4V. For other I/O standards, see the table "Delay Measurement Methodology," page 60.

IOB Output Switching Characteristics

Output delays terminating at a pad are specified for LVTTL with 12 mA drive and fast slew rate. For other standards, adjust the delays with the values shown in "IOB Output Delay Adjustments for Different Standards," page 59.

			Speed	Grade		
		-6		-5		
Symbol	Description	Min	Max	Min	Max	Units
Propagation Delays	5					
T _{IOOP}	O input to pad	-	2.9	-	3.4	ns
T _{IOOLP}	O input to pad via transparent latch	-	3.4	-	4.0	ns
3-state Delays		1				
T _{IOTHZ}	T input to pad high-impedance ⁽¹⁾	-	2.0	-	2.3	ns
T _{IOTON}	T input to valid data on pad	-	3.0	-	3.6	ns
T _{IOTLPHZ}	T input to pad high impedance via transparent latch ⁽¹⁾	-	2.5	-	2.9	ns
T _{IOTLPON}	T input to valid data on pad via transparent latch	-	3.5	-	4.2	ns
T _{GTS}	GTS to pad high impedance ⁽¹⁾	-	5.0	-	5.9	ns
Sequential Delays		1	L	1		
T _{IOCKP}	Clock CLK to pad	-	2.9	-	3.4	ns
Т _{ЮСКНZ}	Clock CLK to pad high impedance (synchronous) ⁽¹⁾	-	2.3	-	2.7	ns
T _{IOCKON}	Clock CLK to valid data on pad (synchronous)	-	3.3	-	4.0	ns
Setup/Hold Times	with Respect to Clock CLK ⁽²⁾	1	l.			
TIOOCK / TIOCKO	O input	1.1/0	-	1.3/0	-	ns
T _{IOOCECK} /	OCE input	0.9 / 0.01	-	0.9/0.01	-	ns
TIOCKOCE						
T _{IOSRCKO} /	SR input (OFF)	1.2/0	-	1.3 / 0	-	ns
TIOCKOSR				/ -		
TIOTCK / TIOCKT	3-state setup times, T input	0.8/0	-	0.9/0	-	ns
Т _{ІОТСЕСК} /	3-state setup times, TCE input	1.0/0	-	1.0/0	-	ns
		11/0		10/0		
	3-state setup times, SK input (TFF)	1.170	-	1.2/0	-	ns
Set/Reset Delays						
	SR input to pad (asynchronous)	_	37	_	44	ns
	SR input to pad high impedance (asynchronous) ⁽¹⁾	-	3.1	-	37	ns
	SR input to valid data on pad (asynchronous)	-	4 1	-	4 Q	ns
	GSR to pad	_	9.1	_	11 7	ns
' IOGSRQ	OUN ID Pau	-	9.9	-	11.7	115

Notes:

1. Three-state turn-off delays should not be adjusted.

2. A zero hold time listing indicates no hold time or a negative hold time.

CLB Arithmetic Switching Characteristics

Setup times not listed explicitly can be approximated by decreasing the combinatorial delays by the setup time adjustment listed. Precise values are provided by the timing analyzer.

		Speed G		I Grade		
		-	6		5	-
Symbol	Description	Min	Мах	Min	Мах	Units
Combinatorial Dela	ays					
T _{OPX}	F operand inputs to X via XOR	-	0.8	-	0.9	ns
T _{OPXB}	F operand input to XB output	-	1.3	-	1.5	ns
T _{OPY}	F operand input to Y via XOR	-	1.7	-	2.0	ns
T _{OPYB}	F operand input to YB output	-	1.7	-	2.0	ns
T _{OPCYF}	F operand input to COUT output	-	1.3	-	1.5	ns
T _{OPGY}	G operand inputs to Y via XOR	-	0.9	-	1.1	ns
T _{OPGYB}	G operand input to YB output	-	1.6	-	2.0	ns
T _{OPCYG}	G operand input to COUT output	-	1.2	-	1.4	ns
T _{BXCY}	BX initialization input to COUT	-	0.9	-	1.0	ns
T _{CINX}	CIN input to X output via XOR	-	0.4	-	0.5	ns
T _{CINXB}	CIN input to XB	-	0.1	-	0.1	ns
T _{CINY}	CIN input to Y via XOR	-	0.5	-	0.6	ns
T _{CINYB}	CIN input to YB	-	0.6	-	0.7	ns
T _{BYP}	CIN input to COUT output	-	0.1	-	0.1	ns
Multiplier Operatio	n					
T _{FANDXB}	F1/2 operand inputs to XB output via AND	-	0.5	-	0.5	ns
T _{FANDYB}	F1/2 operand inputs to YB output via AND	-	0.9	-	1.1	ns
T _{FANDCY}	F1/2 operand inputs to COUT output via AND	-	0.5	-	0.6	ns
T _{GANDYB}	G1/2 operand inputs to YB output via AND	-	0.6	-	0.7	ns
T _{GANDCY}	G1/2 operand inputs to COUT output via AND		0.2	-	0.2	ns
Setup/Hold Times	with Respect to Clock CLK ⁽¹⁾					
Т _{ССКХ} / Т _{СКСХ}	CIN input to FFX	1.1/0	-	1.2/0	-	ns
T _{CCKY} / T _{CKCY}	CIN input to FFY	1.2 / 0	-	1.3/0	-	ns

Notes:

1. A zero hold time listing indicates no hold time or a negative hold time.

Block RAM Switching Characteristics

		Speed Grade				
		-6		-5		
Symbol	Description	Min	Max	Min	Max	Units
Sequential Delays		<u>.</u>	<u>.</u>	<u>.</u>	<u>.</u>	<u></u>
Т _{ВСКО}	Clock CLK to DOUT output	-	3.4	-	4.0	ns
Setup/Hold Times with Respect to Clock CLK ⁽¹⁾						
T _{BACK} / T _{BCKA}	ADDR inputs	1.4 / 0	-	1.4 / 0	-	ns
T _{BDCK} / T _{BCKD}	DIN inputs	1.4 / 0	-	1.4 / 0	-	ns
T _{BECK} / T _{BCKE}	EN inputs	2.9 / 0	-	3.2 / 0	-	ns
T _{BRCK} / T _{BCKR}	RST input	2.7 / 0	-	2.9/0	-	ns
T _{BWCK} / T _{BCKW}	WEN input	2.6 / 0	-	2.8 / 0	-	ns
Clock CLK						
T _{BPWH}	Minimum pulse width, High	-	1.9	-	1.9	ns
T _{BPWL}	Minimum pulse width, Low	-	1.9	-	1.9	ns
T _{BCCS}	CLKA -> CLKB setup time for different ports	-	3.0	-	4.0	ns

Notes:

1. A zero hold time listing indicates no hold time or a negative hold time.

TBUF Switching Characteristics

		Speed	Speed Grade		
		-6	-5	-	
Symbol	Symbol Description		Max	Units	
Combinatorial Delay	rs			<u>.</u>	
T _{IO}	IN input to OUT output	0	0	ns	
T _{OFF}	TRI input to OUT output high impedance	0.1	0.2	ns	
T _{ON}	TRI input to valid data on OUT output	0.1	0.2	ns	

JTAG Test Access Port Switching Characteristics

			Speed	l Grade		
		-6		-5		
Symbol	Description	Min	Max	Min	Max	Units
Setup and Hold Times with Respect to TCK						
T _{TAPTCK /} T _{TCKTAP}	TMS and TDI setup and hold times	4.0/2.0	-	4.0/2.0	-	ns
Sequential Delays	-	· · ·				
T _{TCKTDO}	Output delay from clock TCK to output TDO	-	11.0	-	11.0	ns
FTCK	Maximum TCK clock frequency	-	33	-	33	MHz

Package	Leads	Туре	Maximum I/O	Lead Pitch (mm)	Footprint Area (mm)	Height (mm)	Mass ⁽¹⁾ (g)
VQ100 / VQG100	100	Very Thin Quad Flat Pack (VQFP)	60	0.5	16 x 16	1.20	0.6
TQ144 / TQG144	144	Thin Quad Flat Pack (TQFP)	92	0.5	22 x 22	1.60	1.4
CS144 / CSG144	144	Chip Scale Ball Grid Array (CSBGA)	92	0.8	12 x 12	1.20	0.3
PQ208 / PQG208	208	Plastic Quad Flat Pack (PQFP)	140	0.5	30.6 x 30.6	3.70	5.3
FG256 / FGG256	256	Fine-pitch Ball Grid Array (FBGA)	176	1.0	17 x 17	2.00	0.9
FG456 / FGG456	456	Fine-pitch Ball Grid Array (FBGA)	284	1.0	23 x 23	2.60	2.2

Table 36: Spartan-II Family Package Options

Notes:

1. Package mass is $\pm 10\%$.

Note: Some early versions of Spartan-II devices, including the XC2S15 and XC2S30 ES devices and the XC2S150 with date code 0045 or earlier, included a power-down pin. For more information, see <u>Answer Record 10500</u>.

VCCO Banks

Some of the I/O standards require specific V_{CCO} voltages. These voltages are externally connected to device pins that serve groups of IOBs, called banks. Eight I/O banks result from separating each edge of the FPGA into two banks (see Figure 3 in Module 2). Each bank has multiple V_{CCO} pins which must be connected to the same voltage. In the smaller packages, the V_{CCO} pins are connected between banks, effectively reducing the number of independent banks available (see Table 37). These interconnected banks are shown in the Pinout Tables with V_{CCO} pads for multiple banks connected to the same pin.

Table 37: Independent VCCO Banks Available

Package	VQ100	CS144	FG256
	PQ208	TQ144	FG456
Independent Banks	1	4	8

Package Overview

Table 36 shows the six low-cost, space-saving productionpackage styles for the Spartan-II family.

Each package style is available in an environmentally friendly lead-free (Pb-free) option. The Pb-free packages include an extra 'G' in the package style name. For example, the standard "CS144" package becomes "CSG144" when ordered as the Pb-free option. Leaded (non-Pb-free) packages may be available for selected devices, with the same pin-out and without the "G" in the ordering code; contact Xilinx sales for more information. The mechanical dimensions of the standard and Pb-free packages are similar, as shown in the mechanical drawings provided in Table 38. For additional package information, see <u>UG112</u>: *Device Package User Guide*.

Mechanical Drawings

Detailed mechanical drawings for each package type are available from the Xilinx web site at the specified location in Table 38.

Material Declaration Data Sheets (MDDS) are also available on the <u>Xilinx web site</u> for each package.

Table 38: Xilinx Package Documentation

Package	Drawing	MDDS
VQ100	Package Drawing	PK173_VQ100
VQG100		PK130_VQG100
TQ144	Package Drawing	PK169_TQ144
TQG144		PK126_TQG144
CS144	Package Drawing	PK149_CS144
CSG144		PK103_CSG144
PQ208	Package Drawing	PK166_PQ208
PQG208		PK123_PQG208
FG256	Package Drawing	PK151_FG256
FGG256		PK105_FGG256
FG456	Package Drawing	PK154_FG456
FGG456		PK109_FGG456

Package Thermal Characteristics

Table 39 provides the thermal characteristics for the various Spartan-II FPGA package offerings. This information is also available using the Thermal Query tool on xilinx.com (www.xilinx.com/cgi-bin/thermal/thermal.pl).

The junction-to-case thermal resistance (θ_{JC}) indicates the difference between the temperature measured on the package body (case) and the die junction temperature per watt of power consumption. The junction-to-board (θ_{JB})

Table	39:	Spartan-II	Package	Thermal	Characteristics
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value similarly reports the difference between the board and junction temperature. The junction-to-ambient (θ_{JA}) value reports the temperature difference between the ambient environment and the junction temperature. The θ_{JA} value is reported at different air velocities, measured in linear feet per minute (LFM). The "Still Air (0 LFM)" column shows the θ_{JA} value in a system without a fan. The thermal resistance drops with increasing air flow.

				Junction-to-Ambient (θ _{JA}) at Different Air Flows				
Package	Device	Junction-to-Case (θ _{JC})	Junction-to- Board (θ _{JB})	Still Air (0 LFM)	250 LFM	500 LFM	750 LFM	Units
VQ100	XC2S15	11.3	N/A	44.1	36.7	34.2	33.3	°C/Watt
VQG100	XC2S30	10.1	N/A	40.7	33.9	31.5	30.8	°C/Watt
	XC2S15	7.3	N/A	38.6	30.0	25.7	24.1	°C/Watt
TQ144	XC2S30	6.7	N/A	34.7	27.0	23.1	21.7	°C/Watt
TQG144	XC2S50	5.8	N/A	32.2	25.1	21.4	20.1	°C/Watt
	XC2S100	5.3	N/A	31.4	24.4	20.9	19.6	°C/Watt
CS144 CSG144	XC2S30	2.8	N/A	34.0	26.0	23.9	23.2	°C/Watt
	XC2S50	6.7	N/A	25.2	18.6	16.4	15.2	°C/Watt
PQ208	XC2S100	5.9	N/A	24.6	18.1	16.0	14.9	°C/Watt
PQG208	XC2S150	5.0	N/A	23.8	17.6	15.6	14.4	°C/Watt
	XC2S200	4.1	N/A	23.0	17.0	15.0	13.9	°C/Watt
	XC2S50	7.1	17.6	27.2	21.4	20.3	19.8	°C/Watt
FG256	XC2S100	5.8	15.1	25.1	19.5	18.3	17.8	°C/Watt
FGG256	XC2S150	4.6	12.7	23.0	17.6	16.3	15.8	°C/Watt
	XC2S200	3.5	10.7	21.4	16.1	14.7	14.2	°C/Watt
FG456	XC2S150	2.0	N/A	21.9	17.3	15.8	15.2	°C/Watt
FGG456	XC2S200	2.0	N/A	21.0	16.6	15.1	14.5	°C/Watt

XC2S15 Device Pinouts (Continued)

XC2S15 Pad Name					Bndry
Function	Bank	VQ100	TQ144	CS144	Scan
GND	-	-	P61	J12	-
I/O (D5)	3	P57	P60	J13	245
I/O	3	P58	P59	H10	248
I/O, V _{REF}	3	P59	P58	H11	251
I/O (D4)	3	P60	P57	H12	254
I/O	3	-	P56	H13	257
V _{CCINT}	-	P61	P55	G12	-
I/O, TRDY ⁽¹⁾	3	P62	P54	G13	260
V _{CCO}	3	P63	P53	G11	-
V _{CCO}	2	P63	P53	G11	-
GND	-	P64	P52	G10	-
I/O, IRDY ⁽¹⁾	2	P65	P51	F13	263
I/O	2	-	P50	F12	266
I/O (D3)	2	P66	P49	F11	269
I/O, V _{REF}	2	P67	P48	F10	272
I/O	2	P68	P47	E13	275
I/O (D2)	2	P69	P46	E12	278
GND	-	-	P45	E11	-
I/O (D1)	2	P70	P44	E10	281
I/O	2	P71	P43	D13	284
I/O, V _{REE}	2	P72	P41	D11	287
I/O	2	-	P40	C13	290
I/O (DIN, D0)	2	P73	P39	C12	293
I/O (DOUT, BUSY)	2	P74	P38	C11	296
CCLK	2	P75	P37	B13	299
V _{CCO}	2	P76	P36	B12	-
V _{CCO}	1	P76	P35	A13	-
TDO	2	P77	P34	A12	-
GND	-	P78	P33	B11	-
TDI	-	P79	P32	A11	-
I/O (CS)	1	P80	P31	D10	0
I/O (WRITE)	1	P81	P30	C10	3
I/O	1	-	P29	B10	6
I/O, V _{REF}	1	P82	P28	A10	9
I/O	1	P83	P27	D9	12
I/O	1	P84	P26	C9	15
GND	-	-	P25	B9	-
V _{CCINT}	-	P85	P24	A9	-
I/O	1	-	P23	D8	18
I/O	1	-	P22	C8	21

XC2S15 Device Pinouts (Continued)

XC2S15 Pad				Bndry	
Function	Bank	VQ100	TQ144	CS144	Scan
I/O, V _{REF}	1	P86	P21	B8	24
I/O	1	-	P20	A8	27
I/O	1	P87	P19	B7	30
I, GCK2	1	P88	P18	A7	36
GND	-	P89	P17	C7	-
V _{CCO}	1	P90	P16	D7	-
V _{CCO}	0	P90	P16	D7	-
I, GCK3	0	P91	P15	A6	37
V _{CCINT}	-	P92	P14	B6	-
I/O	0	-	P13	C6	44
I/O, V _{REF}	0	P93	P12	D6	47
I/O	0	-	P11	A5	50
I/O	0	-	P10	B5	53
V _{CCINT}	-	P94	P9	C5	-
GND	-	-	P8	D5	-
I/O	0	P95	P7	A4	56
I/O	0	P96	P6	B4	59
I/O, V _{REF}	0	P97	P5	C4	62
I/O	0	-	P4	A3	65
I/O	0	P98	P3	B3	68
ТСК	-	P99	P2	C3	-
V _{CCO}	0	P100	P1	A2	-
V _{CCO}	7	P100	P144	B2	-

04/18/01

Notes:

- 1. IRDY and TRDY can only be accessed when using Xilinx PCI cores.
- 2. See "VCCO Banks" for details on V_{CCO} banking.

Additional XC2S15 Package Pins

VQ100

Not Connected Pins								
P28	P29	-	-	-	-			
11/02/00								

TQ144

Not Connected Pins								
P42	P64	P78	P101	P104	P105			
P116	P138	-	-	-	-			
11/02/00		•						

CS144

00144								
Not Connected Pins								
D3	D12	J4	K13	M3	M4			
M10	N3	-	-	-	-			
11/02/00								

XC2S100 Pad Name						Brdry
Function	Bank	TQ144	PQ208	FG256	FG456	Scan
I/O, V _{REF}	4	P79	P95	T11	AB16	502
I/O	4	-	-	-	AB17	505
I/O	4	P78	P96	N11	V15	508
I/O	4	-	-	R12	Y16	511
I/O	4	-	P97	P11	AB18	517
I/O, V _{REF}	4	P77	P98	T12	AB19	520
V _{CCO}	4	-	-	V _{CCO} Bank 4*	V _{CCO} Bank 4*	-
GND	-	-	-	GND*	GND*	-
I/O	4	-	P99	T13	Y17	523
I/O	4	-	-	N12	V16	526
I/O	4	-	-	-	W17	529
I/O	4	P76	P100	R13	AB20	532
I/O	4	-	-	P12	AA19	535
I/O	4	P75	P101	P13	AA20	541
I/O	4	P74	P102	T14	W18	544
GND	-	P73	P103	GND*	GND*	-
DONE	3	P72	P104	R14	Y19	547
V _{CCO}	4	P71	P105	V _{CCO} Bank 4*	V _{CCO} Bank 4*	-
V _{CCO}	3	P70	P105	V _{CCO} Bank 3*	V _{CCO} Bank 3*	-
PROGRAM	-	P69	P106	P15	W20	550
I/O (INIT)	3	P68	P107	N15	V19	551
I/O (D7)	3	P67	P108	N14	Y21	554
I/O	3	-	-	T15	W21	560
I/O	3	P66	P109	M13	U20	563
I/O	3	-	-	-	U19	566
I/O	3	-	-	R16	T18	569
I/O	3	-	P110	M14	W22	572
GND	-	-	-	GND*	GND*	-
V _{CCO}	3	-	-	V _{CCO} Bank 3*	V _{CCO} Bank 3*	-
I/O, V _{REF}	3	P65	P111	L14	U21	575
I/O	3	-	P112	M15	T20	578
I/O	3	-	-	L12	T21	584
I/O	3	P64	P113	P16	R18	587
I/O	3	-	-	-	U22	590
I/O, V _{REF}	3	P63	P114	L13	R19	593
I/O (D6)	3	P62	P115	N16	T22	596
GND	-	P61	P116	GND*	GND*	-

XC2S100 Device Pinouts (Continued)

XC2S100 Pad Name						Bndry
Function	Bank	TQ144	PQ208	FG256	FG456	Scan
V _{CCO}	3	-	P117	V _{CCO} Bank 3*	V _{CCO} Bank 3*	-
V _{CCINT}	-	-	P118	V _{CCINT} *	V_{CCINT}^{*}	-
I/O (D5)	3	P60	P119	M16	R21	599
I/O	3	P59	P120	K14	P18	602
I/O	3	-	-	L16	P20	605
I/O	3	-	P121	K13	P21	608
I/O	3	-	P122	L15	N18	614
I/O	3	-	P123	K12	N20	617
GND	-	-	P124	GND*	GND*	-
I/O, V _{REF}	3	P58	P125	K16	N21	620
I/O (D4)	3	P57	P126	J16	N22	623
I/O	3	-	-	J14	M19	626
I/O	3	P56	P127	K15	M20	629
V _{CCINT}	-	P55	P128	E5	V _{CCINT} *	-
I/O, TRDY ⁽¹⁾	3	P54	P129	J15	M22	638
V _{CCO}	3	P53	P130	V _{CCO} Bank 3*	V _{CCO} Bank 3*	-
V _{CCO}	2	P53	P130	V _{CCO} Bank 2*	V _{CCO} Bank 2*	-
GND	-	P52	P131	GND*	GND*	-
I/O, IRDY ⁽¹⁾	2	P51	P132	H16	L20	641
I/O	2	-	P133	H14	L17	644
I/O	2	P50	P134	H15	L21	650
I/O	2	-	-	J13	L22	653
I/O (D3)	2	P49	P135	G16	K20	656
I/O, V _{REF}	2	P48	P136	H13	K21	659
GND	-	-	P137	GND*	GND*	-
I/O	2	-	P138	G14	K22	662
I/O	2	-	P139	G15	J21	665
I/O	2	-	P140	G12	J18	671
I/O	2	-	-	F16	J22	674
I/O	2	P47	P141	G13	H19	677
I/O (D2)	2	P46	P142	F15	H20	680
V _{CCINT}	-	-	P143	V _{CCINT} *	V _{CCINT} *	-
V _{CCO}	2	-	P144	V _{CCO} Bank 2*	V _{CCO} Bank 2*	-
GND	-	P45	P145	GND*	GND*	-
I/O (D1)	2	P44	P146	E16	H22	683
I/O, V _{REF}	2	P43	P147	F14	H18	686
I/O	2	-	-	-	G21	689
I/O	2	P42	P148	D16	G18	692

XC2S150 Device Pinouts

XC2S150 Pad Name					Bndry
Function	Bank	PQ208	FG256	FG456	Scan
GND	-	P1	GND*	GND*	-
TMS	-	P2	D3	D3	-
I/O	7	P3	C2	B1	221
I/O	7	-	-	E4	224
I/O	7	-	-	C1	227
I/O	7	-	A2	F5	230
GND	-	-	GND*	GND*	-
I/O	7	P4	B1	D2	233
I/O	7	-	-	E3	236
I/O	7	-	-	F4	239
I/O	7	-	E3	G5	242
I/O	7	P5	D2	F3	245
GND	-	-	GND*	GND*	-
V _{CCO}	7	-	V _{CCO} Bank 7*	V _{CCO} Bank 7*	-
I/O, V _{REF}	7	P6	C1	E2	248
I/O	7	P7	F3	E1	251
I/O	7	-	-	G4	254
I/O	7	-	-	G3	257
I/O	7	-	E2	H5	260
I/O	7	P8	E4	F2	263
I/O	7	-	-	F1	266
I/O, V _{REF}	7	P9	D1	H4	269
I/O	7	P10	E1	G1	272
GND	-	P11	GND*	GND*	-
V _{CCO}	7	P12	V _{CCO} Bank 7*	V _{CCO} Bank 7*	-
V _{CCINT}	-	P13	V _{CCINT} *	V _{CCINT} *	-
I/O	7	P14	F2	H3	275
I/O	7	P15	G3	H2	278
I/O	7	-	-	H1	284
I/O	7	-	F1	J5	287
I/O	7	P16	F4	J2	290
I/O	7	-	-	J3	293
I/O	7	P17	F5	K5	299
I/O	7	P18	G2	K1	302
GND	-	P19	GND*	GND*	-
V _{CCO}	7	-	V _{CCO} Bank 7*	V _{CCO} Bank 7*	-
I/O, V _{REF}	7	P20	H3	K3	305
I/O	7	P21	G4	K4	308
I/O	7	-	H2	L6	311

XC2S150 Device Pinouts (Continued)

XC2S150 Pad Name					Bndry
Function	Bank	PQ208	FG256	FG456	Scan
I/O	7	P22	G5	L1	314
I/O	7	-	-	L5	317
I/O	7	P23	H4	L4	320
I/O, IRDY ⁽¹⁾	7	P24	G1	L3	323
GND	-	P25	GND*	GND*	-
V _{CCO}	7	P26	V _{CCO} Bank 7*	V _{CCO} Bank 7*	-
V _{CCO}	6	P26	V _{CCO} Bank 6*	V _{CCO} Bank 6*	-
I/O, TRDY ⁽¹⁾	6	P27	J2	M1	326
V _{CCINT}	-	P28	V_{CCINT}^{*}	V_{CCINT}^{*}	-
I/O	6	-	-	M6	332
I/O	6	P29	H1	M3	335
I/O	6	-	J4	M4	338
I/O	6	P30	J1	M5	341
I/O, V _{REF}	6	P31	J3	N2	344
V _{CCO}	6	-	V _{CCO} Bank 6*	V _{CCO} Bank 6*	-
GND	-	P32	GND*	GND*	-
I/O	6	P33	K5	N3	347
I/O	6	P34	K2	N4	350
I/O	6	-	-	N5	356
I/O	6	P35	K1	P2	359
I/O	6	-	K3	P4	362
I/O	6	-	-	R1	365
I/O	6	P36	L1	P3	371
I/O	6	P37	L2	R2	374
V _{CCINT}	-	P38	V _{CCINT} *	V _{CCINT} *	-
V _{CCO}	6	P39	V _{CCO} Bank 6*	V _{CCO} Bank 6*	-
GND	-	P40	GND*	GND*	-
I/O	6	P41	K4	T1	377
I/O, V _{REF}	6	P42	M1	R4	380
I/O	6	-	-	T2	383
I/O	6	P43	L4	U1	386
I/O	6	-	M2	R5	389
I/O	6	-	-	V1	392
I/O	6	-	-	T5	395
I/O	6	P44	L3	U2	398
I/O, V _{REF}	6	P45	N1	Т3	401
V _{CCO}	6	-	V _{CCO} Bank 6*	V _{CCO} Bank 6*	-
GND	-	-	GND*	GND*	-

XC2S200 Device Pinouts (Continued)

XC2S200 Pad Name					Bndry
Function	Bank	PQ208	FG256	FG456	Scan
GND	-	P198	GND*	GND*	-
I/O	0	P199	A5	B7	188
I/O, V _{REF}	0	P200	C6	E8	191
I/O	0	-	-	D8	197
I/O	0	P201	B5	C7	200
GND	-	-	GND*	GND*	-
I/O	0	-	D6	D7	203
I/O	0	-	-	B6	206
I/O	0	-	-	A5	209
I/O	0	P202	A4	D6	212
I/O, V _{REF}	0	P203	B4	C6	215
V _{CCO}	0	-	V _{CCO} Bank 0*	V _{CCO} Bank 0*	-
GND	-	-	GND*	GND*	-
I/O	0	P204	E6	B5	218
I/O	0	-	D5	E7	221
I/O	0	-	-	A4	224
I/O	0	-	-	E6	230
I/O, V _{REF}	0	P205	A3	B4	233
GND	-	-	GND*	GND*	-
I/O	0	-	C5	A3	236
I/O	0	-	-	B3	239
I/O	0	-	-	D5	242
I/O	0	P206	B3	C5	248
ТСК	-	P207	C4	C4	-
V _{cco}	0	P208	V _{CCO} Bank 0*	V _{CCO} Bank 0*	-
V _{CCO}	7	P208	V _{CCO} Bank 7*	V _{CCO} Bank 7*	-

04/18/01

- 1. IRDY and TRDY can only be accessed when using Xilinx PCI cores.
- Pads labelled GND*, V_{CCINT}*, V_{CCO} Bank 0*, V_{CCO} Bank 1*, V_{CCO} Bank 2*, V_{CCO} Bank 3*, V_{CCO} Bank 4*, V_{CCO} Bank 5*, V_{CCO} Bank 6*, V_{CCO} Bank 7* are internally bonded to independent ground or power planes within the package.
- 3. See "VCCO Banks" for details on V_{CCO} banking.

Additional XC2S200 Package Pins

PQ208

Not Connected Pins								
P55	P56	-	-	-	-			
11/02/00		•	•					

FG256

	V _{CCINT} Pins									
C3	C14	D4	D13	E5	E12					
M5	M12	N4	N13	P3	P14					
	V _{CCO} Bank 0 Pins									
E8	F8	-	-	-	-					
V _{CCO} Bank 1 Pins										
E9	F9	-	-	-	-					
		V _{CCO} Ba	nk 2 Pins							
H11	H12	-	-	-	-					
		V _{CCO} Ba	nk 3 Pins							
J11	J12	-	-	-	-					
		V _{CCO} Ba	nk 4 Pins							
L9	M9	-	-	-	-					
	V _{CCO} Bank 5 Pins									
L8	M8	-	-	-	-					
		V _{CCO} Ba	nk 6 Pins							
J5	J6	-	-	-	-					
		V _{CCO} Ba	nk 7 Pins							
H5	H6	-	-	-	-					
		GND	Pins							
A1	A16	B2	B15	F6	F7					
F10	F11	G6	G7	G8	G9					
G10	G11	H7	H8	H9	H10					
J7	J8	J9	J10	K6	K7					
K8	K9	K10	K11	L6	L7					
L10	L11	R2	R15	T1	T16					
		Not Conne	ected Pins							
P4	R4	-	-	-	-					

Additional XC2S200 Package Pins (Continued)

11/02/00

FG456								
		V _{CCIN}	_T Pins					
E5	E18	F6	F17	G7	G8			
G9	G14	G15	G16	H7	H16			
J7	J16	P7	P16	R7	R16			
T7	T8	Т9	T14	T15	T16			
U6	U17	V5	V18	-	-			
	L	V _{CCO} Ba	nk 0 Pins					
F7	F8	F9	F10	G10	G11			
	V _{CCO} Bank 1 Pins							
F13	F14	F15	F16	G12	G13			
		V _{CCO} Ba	nk 2 Pins					
G17	H17	J17	K16	K17	L16			
		V _{CCO} Ba	nk 3 Pins					
M16	N16	N17	P17	R17	T17			
		V _{CCO} Ba	nk 4 Pins					
T12	T13	U13	U14	U15	U16			
		V _{CCO} Ba	nk 5 Pins					
T10	T11	U7	U8	U9	U10			
		V _{CCO} Ba	nk 6 Pins		·			
M7	N6	N7	P6	R6	T6			
	V _{CCO} Bank 7 Pins							

Additional XC2S200 Package Pins (Continued)

G6	H6	J6	K6	K7	L7	
GND Pins						
A1	A22	B2	B21	C3	C20	
J9	J10	J11	J12	J13	J14	
K9	K10	K11	K12	K13	K14	
L9	L10	L11	L12	L13	L14	
M9	M10	M11	M12	M13	M14	
N9	N10	N11	N12	N13	N14	
P9	P10	P11	P12	P13	P14	
Y3	Y20	AA2	AA21	AB1	AB22	
Not Connected Pins						
A2	A6	A12	B11	B16	C2	
D1	D4	D18	D19	E17	E19	
G2	G22	L2	L19	M2	M21	
R3	R20	U3	U18	V6	W4	
W19	Y5	Y22	AA1	AA3	AA11	
AA16	AB7	AB12	AB21	-	-	
11/02/00						

Revision History

Version	Date	Description
110.	Dute	Description
2.0	09/18/00	Sectioned the Spartan-II Family data sheet into four modules. Corrected all known errors in the pinout tables.
2.1	10/04/00	Added notes requiring PWDN to be tied to V _{CCINT} when unused.
2.2	11/02/00	Removed the Power Down feature.
2.3	03/05/01	Added notes on pinout tables for IRDY and TRDY.
2.4	04/30/01	Reinstated XC2S50 V _{CCO} Bank 7, GND, and "not connected" pins missing in version 2.3.
2.5	09/03/03	Added caution about Not Connected Pins to XC2S30 pinout tables on page 76.
2.8	06/13/08	Added "Package Overview" section. Added notes to clarify shared V _{CCO} banks. Updated description and links. Updated all modules for continuous page, figure, and table numbering. Synchronized all modules to v2.8.